

### **40V N-Channel Power MOSFET**

# **Product Summary**

V <sub>(BR)DSS</sub>	R <sub>DS(on)TYP</sub>	I <sub>D</sub>	
40V	0.7mΩ@10V	4004	
	1.2mΩ@4.5V	400A	



#### **Feature**

- Fast Switching
- Low Gate Charge and Rdson
- Advanced Split Gate Trench Technology
- 100% Single Pulse avalanche energy Test

# **Applications**

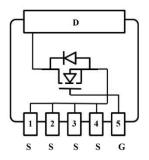
- PWM Application
- Hard switched and high frequency circuits
- Power Management

### **Package**



sTOLL

# Circuit diagram



### Marking



SP40N01AGMT :Device Code \*\* :Week Code

### **Order Information**

Device	Package	Unit/Tape
SP40N01AGMT	sTOLL	2000



Absolute maximum ratings (Ta=25℃,unless otherwise noted)

Parameter	Symbol	Rating	Units
Drain-Source Voltage	$V_{DS}$	40	V
Gate-Source Voltage	V <sub>GS</sub>	±20	V
Continuous Drain Current(Tc=25℃)	I <sub>D</sub>	400	Α
Continuous Drain Current(Tc=100℃)	I <sub>D</sub>	267	Α
Pulsed Drain Current	I <sub>DM</sub>	1200	Α
Single Pulse Avalanche Energy <sup>1</sup>	E <sub>AS</sub>	1506	mJ
Total Power Dissipation(Tc=25℃)	P <sub>D</sub>	327	W
Thermal Resistance Junction-to-Case	R <sub>0</sub> JC	0.38	°C/W
Storage Temperature Range	T <sub>STG</sub>	-55 to 150	℃
Operating Junction Temperature Range	TJ	-55 to 150	°C

Electrical characteristics (Ta=25℃, unless otherwise noted)

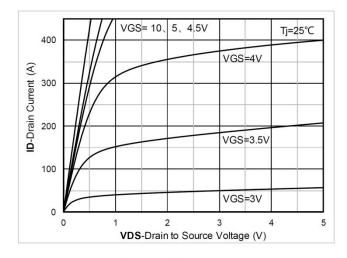
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Static Characteristics						
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	VGS=0V , ID=250uA	40	-	-	V
Drain-Source Leakage Current	I <sub>DSS</sub>	VDS=32V , VGS=0V , TJ=25℃	-	-	1	uA
Gate-Source Leakage Current	I <sub>GSS</sub>	VGS=±20V, VDS=0V	-	-	±100	nA
Gate Threshold Voltage	V <sub>GS(th)</sub>	VGS=VDS , ID =250uA	1	1.7	2.5	V
Static Drain-Source On-Resistance	В	VGS=10V, ID=30A	-	0.7	0.95	mΩ
Static Drain-Source On-Resistance	R <sub>DS(ON)</sub>	VGS=4.5V , ID=30A	-	1.2	1.6	
Dynamic characteristics						
Input Capacitance	C <sub>iss</sub>		-	7300	-	
Output Capacitance	Coss	VDS=20V , VGS=0V , f=1MHz	-	3550	-	pF
Reverse Transfer Capacitance	Crss	1		145	-	
Total Gate Charge	Qg	VDS=20V , VGS=10V , ID=50A	-	98	-	nC
Gate-Source Charge	Qgs		-	19	-	
Gate-Drain Charge	$Q_{gd}$	1		17	-	
Switching Characteristics						
Turn-On Delay Time	T <sub>d(on)</sub>		-	13.5	-	
Rise Time	Tr	İ	-	35.8	-	
Turn-Off Delay Time	T <sub>d(off)</sub>	VDD=20V , VGS=10V , RG=1.6Ω, ID=50A		66	-	nS
Fall Time	T <sub>f</sub>			24.8	-	
Diode Characteristics						
Diode Forward Voltage	V <sub>SD</sub>	VGS=0V , I <sub>S</sub> =1A , TJ=25℃	-	-	1.2	V
Maximum Body-Diode Continuous Current	Is		-	-	400	Α
Reverse Recovery Time	Trr	ls=50A, di/dt=100A/us, TJ=25℃		68	-	nS
Reverse Recovery Charge	Qrr			95	-	nC

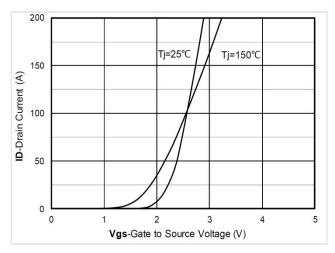
#### Note:

**1.** The test condition is VDD=20V,VGS=10V,L=0.5mH,RG=25 $\Omega$ 

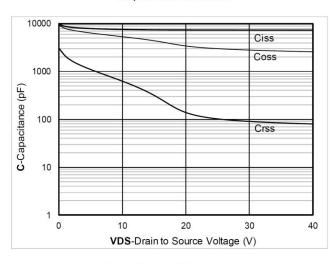


# **Typical Characteristics**

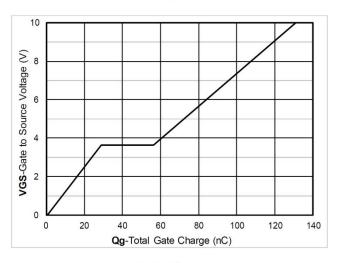




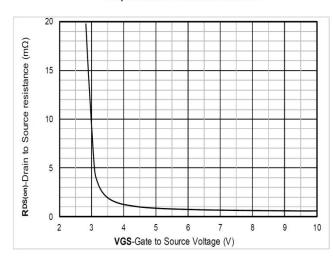
**Output Characteristics** 



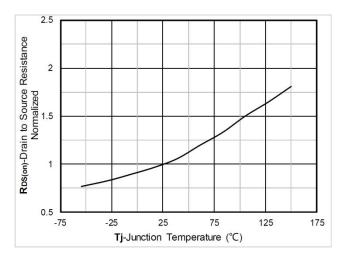
**Transfer Characteristics** 



Capacitance Characteristics



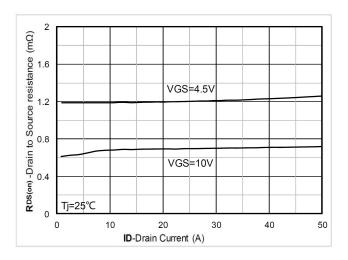
Gate Charge

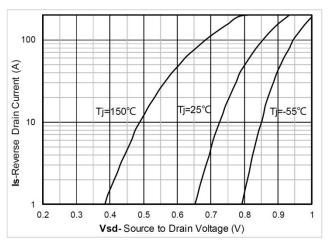


On-Resistance vs Gate to Source Voltage

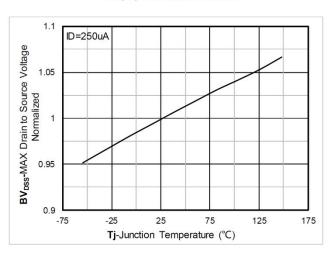
Normalized On-Resistance



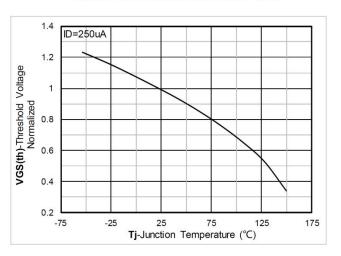




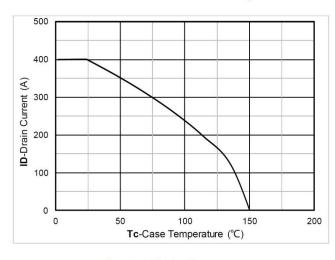
RDS(on) VS Drain Current



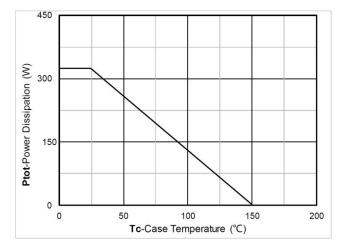
Forward characteristics of reverse diode



Normalized breakdown voltage

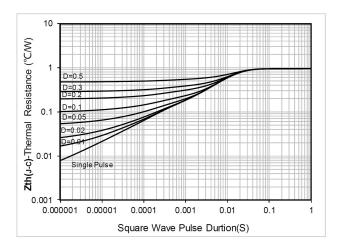


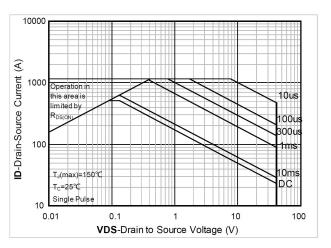
Normalized Threshold voltage



Current dissipation

Power dissipation



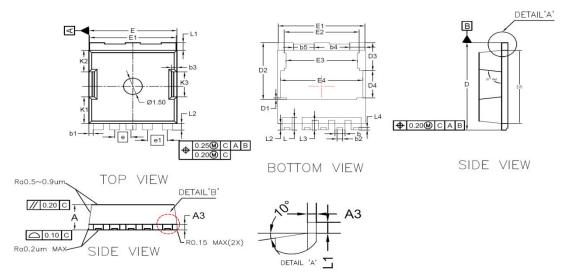


Maximum Transient Thermal Impedance

Safe Operation Area



# **sTOLL Package Information**



0 1 1	Dimensions In Millimeters				
Symbol	MIN	NOM	MAX		
Α	2. 262	2.300	2.338		
A3	0. 492	0. 500	0. 508		
D	7.950	8. 000	8. 050		
D5	6. 650	6.700	6.750		
E	6.950	7. 000	7.050		
е		1.30 BCS			
e1		1.60 BCS			
D1		0.130 ref			
D2	5.150	5.200	5. 250		
D3	2. 520	2. 570	2. 620		
D4	2.450	2.500	2.550		
b	0. 750	0.800	0. 850		
b1		0.350 ref			
b2	0.350	0.450	0.550		
b3	0.400	0.425	0.450		
b4	1.100	1.200	1. 300		
b5	1. 550	1.650	1.750		
L	1.100	1.150	1.200		
L1	0. 650	0.700	0.750		
L2	0. 550	0. 600	0. 650		
L3	0.850	0.900	0.950		
L4	0. 185	0.235	0. 285		
E1	6. 850	6. 900	6. 950		
E2	5. 910	5. 960	6. 010		
E3	5. 610	5. 660	5.710		
E4	6.510	6.560	6. 610		
K1	2.430 ref				
K2		1.970 ref			
K3	2.275	2.300	2.325		